

Spec. No.: HL4710-8P050B-BNNN

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# SPECIFICATION

Model Name: Reflective Blood Sensor

Model NO. : HL4710-8P050B-B

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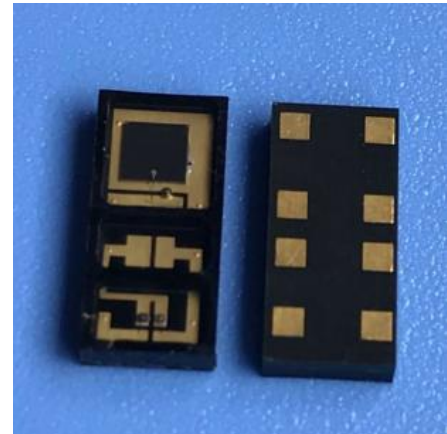
<http://www.szwhaley.com/>

## ■Features

- Lead frame molded packages
- 8-pin leadless ceramic substrate
- Bi-wavelengths or triple wavelengths LEDs
- Matching detector response

## ■Applications

- SPO2
- Blood analysis
- Medical instrumentation
- Radiometric instruments



| Name                         | Model          | RED    | IR    | PD          | Package    |
|------------------------------|----------------|--------|-------|-------------|------------|
| Reflector<br>Blood<br>Sensor | HL4710-8P050-A | 660 nm | 905nm | 2.29*2.29mm | 8-Pin, COB |

## ■Absolute Maximum Ratings

(Ta= 25℃)

| Parameter             | Symbol           | Max.     | Unit | Note                              |
|-----------------------|------------------|----------|------|-----------------------------------|
| Power Dissipation     | P <sub>d</sub>   | 60       | mW   | ---                               |
| Forward Current       | I <sub>F</sub>   | 20       | mA   | ---                               |
| Peak Forward Current  | IFP              | 100      | mA   | 1/10 Duty cycle,0.1ms pulse width |
| Reverse Voltage       | V <sub>R</sub>   | 5        | V    | ---                               |
| Operating Temperature | T <sub>opr</sub> | -25~+85  | ℃    | ---                               |
| Storage Temperature   | T <sub>Stg</sub> | -40~+100 | ℃    | ---                               |
| Soldering Temperature | T <sub>S01</sub> | 260      | ℃    | 260℃ for 3 Seconds                |

## ■Electrical/Optical Characteristics

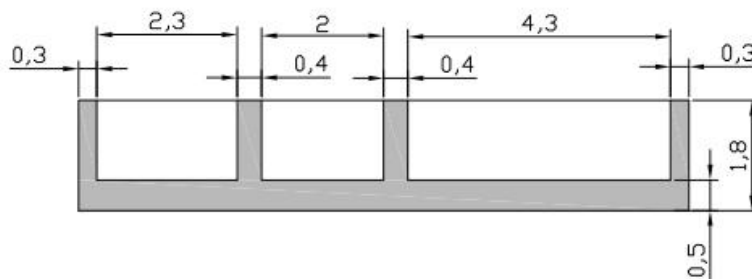
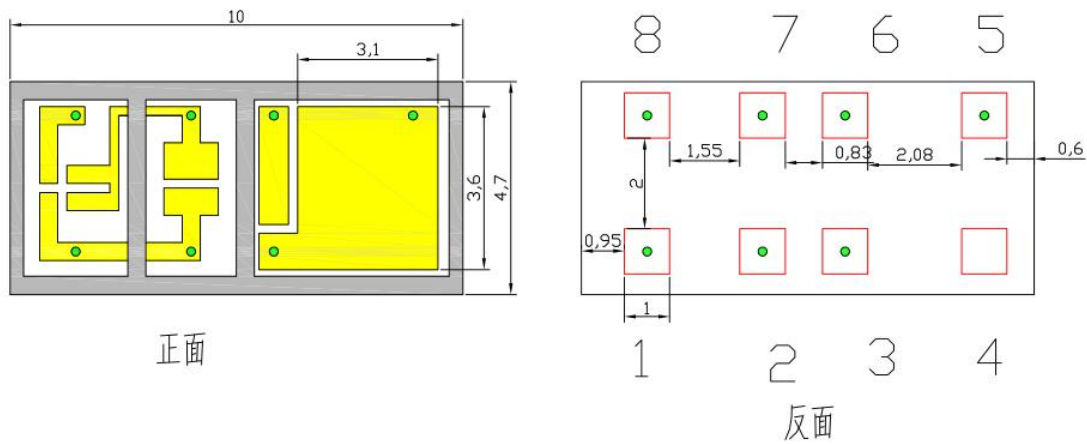
(Ta= 25℃)

| Parameter                | Symbol         | Min. |     | Typ. |     | Max. |     | Units | Test Conditions |
|--------------------------|----------------|------|-----|------|-----|------|-----|-------|-----------------|
|                          |                | 905  | 660 | 905  | 660 | 905  | 660 |       |                 |
| Forward Voltage          | V <sub>F</sub> | --   | 1.8 | 1.35 | --  | 1.75 | 2.3 | V     | IF=20mA         |
| Reverse Current          | I <sub>R</sub> | --   | --  | --   | --  | 10   | 10  | uA    | VR=5V           |
| Radiant Power            | P <sub>o</sub> | 1.5  | 4   | 3    | 9   | 4    | 11  | mW    | IF=20mA         |
| Peak Wavelength          | λ <sub>p</sub> | --   | --  | 895  | 660 | --   | --  | nm    | IF=20mA         |
| Spectral Line Half-width | Δλ             | --   | --  | 50   | 15  | --   | --  | nm    | IF=20mA         |

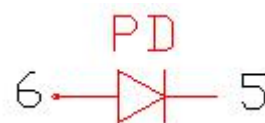
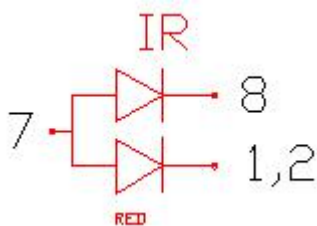
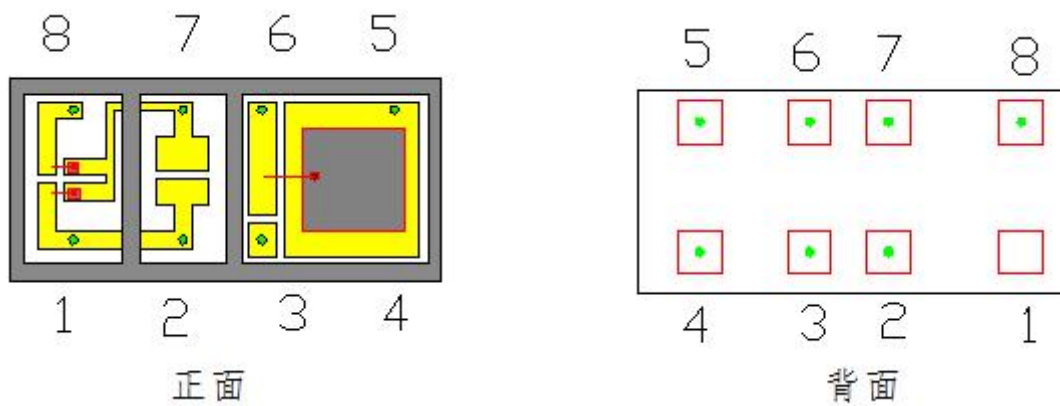
**PD:**

| Parameter(参数)             | Symbol          | Min. | Typ. | Max. | Units | Test Conditions             |
|---------------------------|-----------------|------|------|------|-------|-----------------------------|
|                           | 符号              | 最小值  | 规格值  | 最大值  | 单位    | 测试条件                        |
| Forward Voltage           | $V_F$           | 0.5  | --   | 1.3  | V     | IF=20mA,H=0                 |
| Reverse Breakdown Voltage | $V_{BR}$        | 35   | --   | --   | V     | IR=100uA,H=0                |
| Reverse Dark Current      | $I_D$           | --   | --   | 20   | nA    | VR=10V,H=0                  |
| Light current             | $I_L$           | --   | 135  | --   | uA    | VR=5V,H as<br>1mw/cm2@940nm |
| Peak Sensing Wavelength   | $\lambda_p$     | --   | 940  | --   | nm    | --                          |
| Spectral Bandwidth        | $\Lambda_{0.5}$ | 400  | --   | 1100 | nm    | --                          |
| Junction Capacitance      | $C_J$           | --   | 5    | --   | pF    | VR=3V,H=0,F=1MHz            |

## Dimension:



比例: 1:10



**Notes:** 1. All dimensions are in millimeters  
2. Tolerances unless dimensions  $\pm 0.1\text{mm}$

**■ Storage and Soldering Condition**

1. Do not open moisture proofs bag before the products are ready to use
2. Before opening the package, the LEDs should be kept at 30°C or less and 90% RH or less.
3. The LEDs should be used within a year.
4. After opening the package, the LEDs should be kept at 30°C or less and 70% RH or less.
5. The LEDs should be used within 168 hours (7 days) after opening the package.
6. If the moisture adsorbent material (silica gel) has fabled away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions. Baking treatment: 60±5°C for 24 hours.
7. When soldering, do not put stress on the LEDs during heating.
8. After soldering, do not warp the circuit board
9. Each terminal is to go to the tip of soldering iron temperature less than 260°C for 5 seconds within once in less than the soldering iron capacity 25W. Leave tow seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.